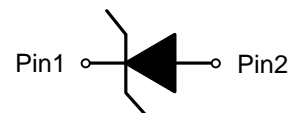


**ESD9X7V**
**1-Line, Uni-directional, Normal capacitance Transient Voltage Suppressor**
<http://www.sh-willsemi.com>
**Descriptions**

The ESD9X7V is a transient voltage suppressor (TVS) which provides a very high level protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). It is designed to replace multilayer varistors (MLV) in consumer equipment applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

The ESD9X7V was past ESD transient voltage up to  $\pm 30\text{kV}$  (contact) according to IEC61000-4-2 and withstand peak current up to 9.5A for 8/20 $\mu\text{s}$  pulse according to IEC61000-4-5.

The ESD9X7V is available in FBP-02C package. Standard products are Pb-free and Halogen-free.


**FBP-02C**

**Pin configuration (Top view)**


\* = Month (A~Z)

J = Device code

**Marking (Top View)**
**Features**

- Working voltage : 7V
- Peak power (tp=8/20 $\mu\text{s}$ ) : 161W
- ESD protection
  - IEC61000-4-2 (Contact) :  $\pm 30\text{kV}$
  - IEC61000-4-2 (Air) :  $\pm 30\text{kV}$
- Low leakage current
- Small package

**Order information**

Device	Package	Shipping
ESD9X7V-2/TR	FBP-02C	10000/Tape&Reel

**Applications**

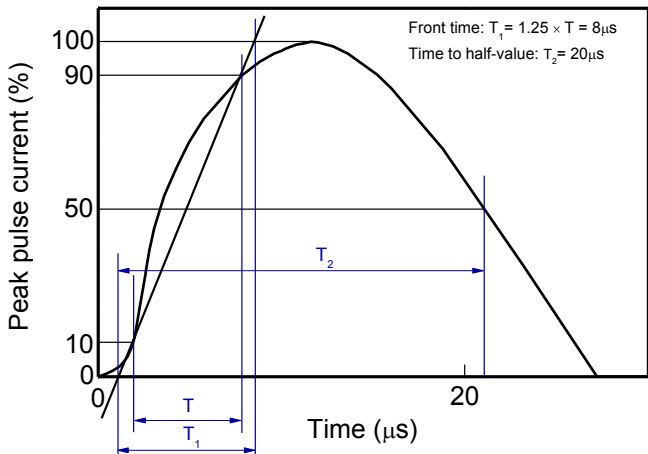
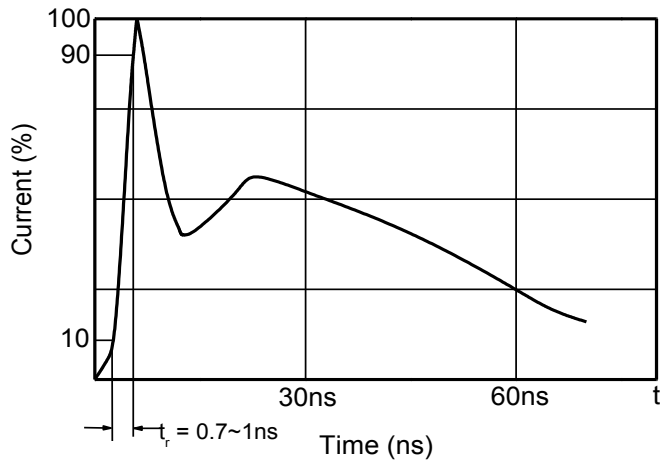
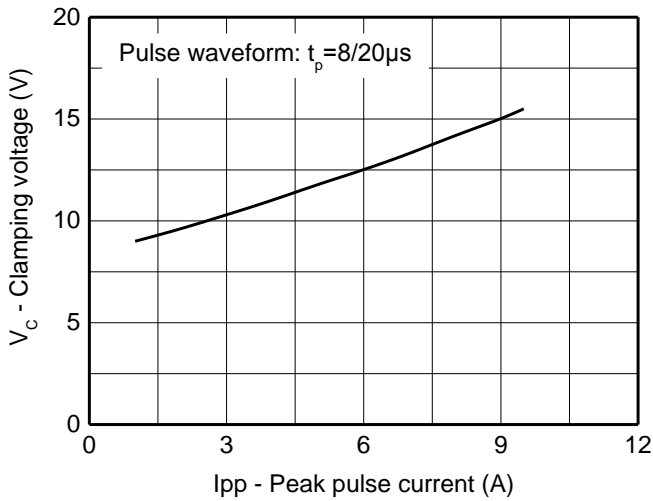
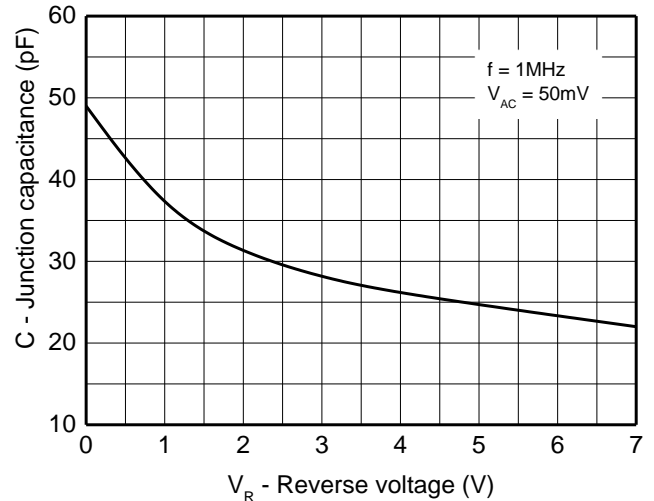
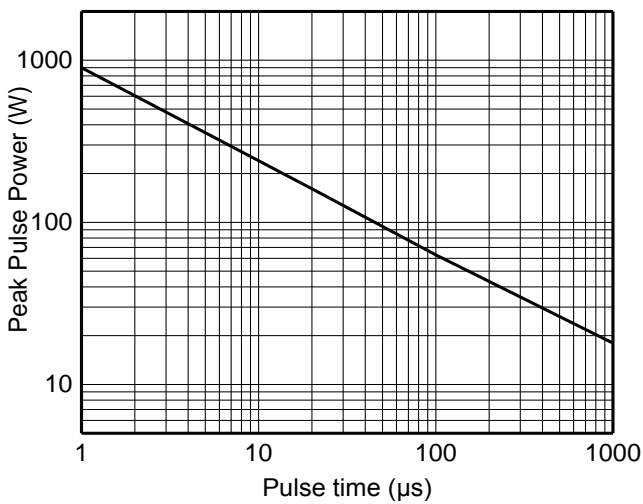
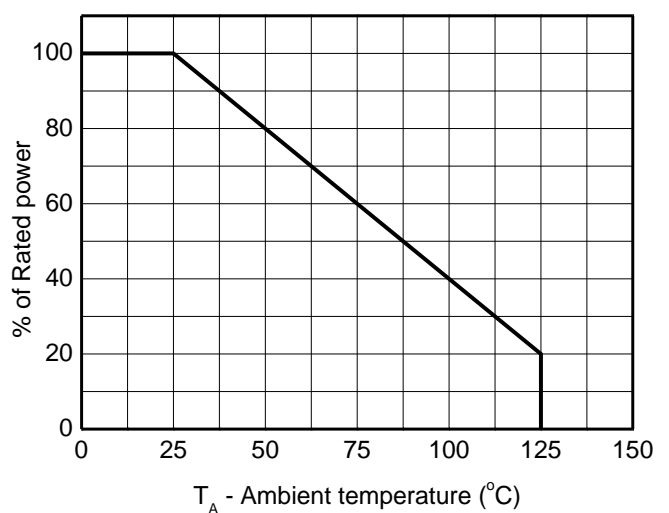
- Mobile phone
- PAD
- Notebook
- STB
- LCD TV
- Digital camera
- Other electronic equipment

**Absolute maximum ratings**

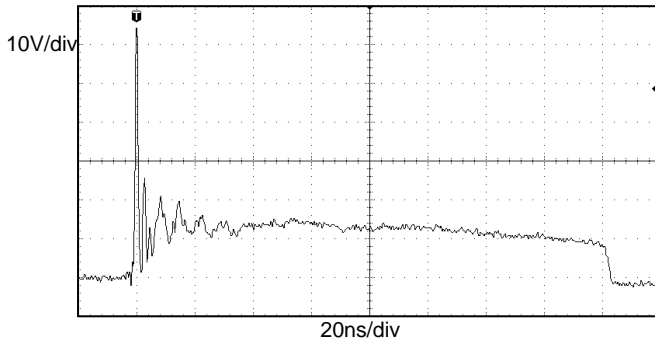
Parameter	Symbol	Rating	Unit
Peak pulse power ( $t_p = 8/20\mu s$ )	Ppk	161	W
Peak pulse current ( $t_p = 8/20\mu s$ )	Ipp	9.5	A
ESD according to IEC61000-4-2 air discharge	V <sub>ESD</sub>	±30	kV
ESD according to IEC61000-4-2 contact discharge		±30	
Junction temperature	T <sub>J</sub>	125	°C
Operating temperature	T <sub>OP</sub>	-40~85	°C
Lead temperature	T <sub>L</sub>	260	°C
Storage temperature	T <sub>STG</sub>	-55~150	°C

**Electronics characteristics (Ta=25 °C, unless otherwise noted)**

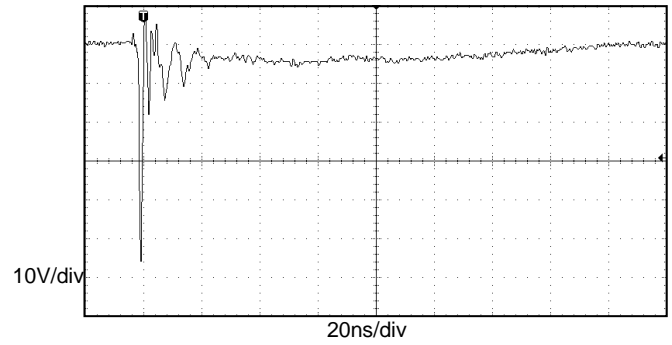
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V <sub>RWM</sub>				7	V
Reverse leakage current	I <sub>R</sub>	V <sub>RWM</sub> =7V			0.05	μA
Reverse breakdown voltage	V <sub>BR</sub>	I <sub>T</sub> =1mA	7.5	8.0	8.8	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =10mA	0.55	0.9	1.25	V
Clamping voltage	V <sub>C</sub>	Ipp=1A, tp=8/20μs			10	V
		Ipp=9.5A, tp=8/20μs			17	V
Junction capacitance	C <sub>J</sub>	f=1MHz, V <sub>R</sub> =0V		49	65	pF

**Typical characteristics (Ta=25°C, unless otherwise noted)**

**8/20 $\mu\text{s}$  waveform per IEC61000-4-5**

**Contact discharge current waveform per IEC61000-4-2**

**Clamping voltage vs. Peak pulse current**

**Capacitance vs. Reverse voltage**

**Non-repetitive peak pulse power vs. Pulse time**

**Power derating vs. Ambient temperature**

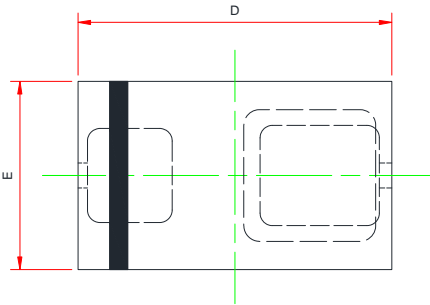
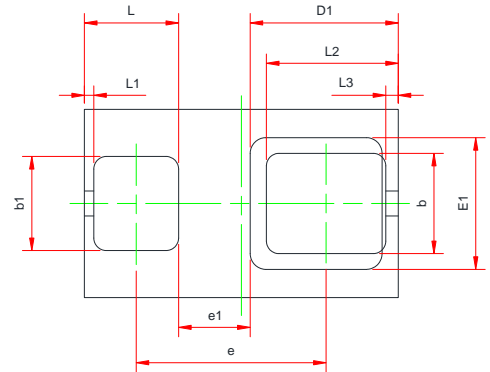
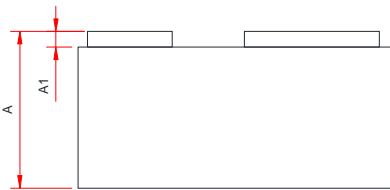
Typical characteristics ( $T_a=25^\circ\text{C}$ , unless otherwise noted)



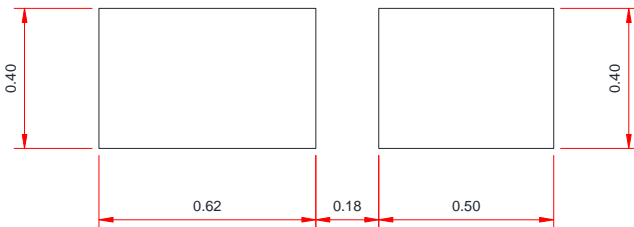
**ESD Clamping**  
**(+8kV contact discharge per IEC61000-4-2)**



**ESD Clamping**  
**(-8kV contact discharge per IEC61000-4-2)**

**Package outline dimensions**
**FBP-02C**

**Top View**

**Bottom View**

**Side View**

Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.450	0.500	0.550
A1	0.010	--	0.100
D	0.950	1.000	1.050
E	0.550	0.600	0.650
D1	0.470 Ref.		
E1	0.420 Ref.		
b	0.270	0.320	0.370
b1	0.250	0.300	0.350
e	0.555	0.605	0.655
e1	0.230 Ref.		
L	0.250	0.300	0.350
L1	0.030 Ref.		
L2	0.370	0.420	0.470
L3	0.040 Ref.		

**Recommend land pattern (Unit: mm)**

**Notes:**

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Willsemi\(韦尔半导体\)](#)